Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1414, RN1415, RN1416, RN1417, RN1418

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- With built-in bias resistors
- Simplified circuit design
- Reduced number of parts and simplified manufacturing process
- Complementary to RN2414 to RN2418

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1414	1	10
RN1415	2.2	10
RN1416	4.7	10
RN1417	10	4.7
RN1418	47	10



Weight: 0.012g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Collector-base voltage	DN1414 to 1418	V _{CBO}	50	V
Collector-emitter voltage	KN1414 10 1418	V _{CEO}	50	V
	RN1414		5	
Emitter-base voltage	RN1415		6	
	RN1416 V _{EBO} RN1417		7	V
			15	
	RN1418		25	
Collector current		Ι _C	100	mA
Collector power dissipation	DN1414 to 1419	PC	200	mW
Junction temperature	RIN1414 10 1416	Tj	150	°C
Storage temperature range		T _{stg}	−55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 1994-08

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1414 to 1418	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
	RN1414 to 1418			V _{CE} = 50V, I _B = 0	_		500	nA
	RN1414			V _{EB} = 5V, I _C = 0	0.35		0.65	
	RN1415			V _{EB} = 6V, I _C = 0	0.37		0.71	
Emitter cut-off current	RN1416	I _{EBO}	-	V _{EB} = 7V, I _C = 0	0.36		0.68	mA
	RN1417			V _{EB} = 15V, I _C = 0	0.78	_	1.46	
	RN1418			V _{EB} = 25V, I _C = 0	0.33	_	0.63	
DC ourrent gain	RN1414 to 16,18			V _{CE} = 5V, I _C = 10mA	50			
DC current gain	RN1417	UFE	_		30			
Collector-emitter saturation voltage	RN1414 to 1418	V _{CE (sat)}	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1414				0.6		2.0	V
	RN1415				0.7		2.5	
Input voltage (ON)	RN1416	V _{I (ON)}	-	V _{CE} = 0.2V, I _C = 5mA	0.8		2.5	
	RN1417				1.5		3.5	
	RN1418				2.5		10.0	
	RN1414	VI (OFF)		V _{CE} = 5V, I _C = 0.1mA	0.3		0.9	V
Input voltage (OFF)	RN1415		_		0.3	_	1.0	
	RN1416				0.3		1.1	
	RN1417				0.3		2.3	
	RN1418				0.5		5.7	
Transition frequency	RN1414 to 1418	f _T	—	V _{CE} = 10V, I _C = 5mA	—	250		MHz
Collector Output capacitance	RN1414 to 1418	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3.0	6.0	pF
	RN1414	R1	_	_	0.7	1.0	1.3	
Input resistor	RN1415				1.54	2.2	2.86	kΩ
	RN1416				3.29	4.7	6.11	
	RN1417				7.0	10.0	13.0	
	RN1418				32.9	47.0	61.1	
Resistor ratio	RN1414			_	_	0.1	-	
	RN1415				_	0.22		
	RN1416	R1/R2	-		_	0.47	_	
	RN1417				_	2.13	_	1
	RN1418				_	4.7	_	1







 $T_{a} = 100^{\circ}C$ $T_{a} = 100^{\circ}C$ T_{a



COLLECTOR CURRENT IC (mA)

Type Name	Marking
RN1414	XQ IIII
RN1415	X S
RN1416	XT U
RN1417	XU XU
RN1418	XW U

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